



10.3Gbps Thunderbolt™ Port and DisplayPort™ Switch

Check for Samples: HD3SS0001

FEATURES

- Compatible with Thunderbolt[™] Technology Electrical Standards and DisplayPort [™]1.2a
- Wide –3dB Differential Bandwidth of Over 10GHz on 10G Path
- Supports DP and DP++ Configurations
- Handles HPD (5V tolerant) and Cable Detect
- Supports AUX and DDC MUX
- Excellent Dynamic Characteristics (on 10G path, typical values at 5GHz):
 - Crosstalk = -35dB
 - Off-Isolation = -24dB
 - Insertion Loss = -1.5dB
 - Return Loss = -20dB
 - Intra-pair Skew Added < 4ps
- Single 3.3V Power Supply
- Small 3x3mm 24-Pin QFN Package
- Low Power Consumption
 - 3.3mW Typical Active Power
 - 80 μW Typical Detect Mode

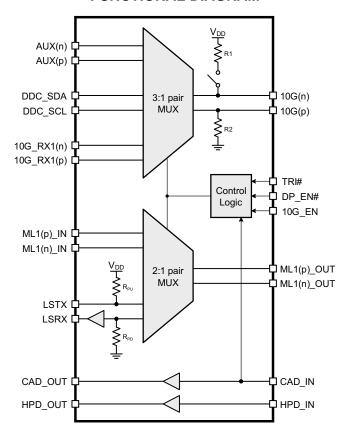
DESCRIPTION

The HD3SS0001 is a high-speed passive-switch device with integrated buffers and resistors, designed to support Thunderbolt™ technology, DisplayPort, and Dual Mode DisplayPort. The 10G path supports a high 10GHz bandwidth and excellent loss characteristics, while the DisplayPort path supports 5.4Gbps.

The integrated 3-pairs to 1-pair multiplexer (3:1 MUX) switches between DDC, AUX, and 10.3Gbps signals. The integrated 2-pairs to 1-pair multiplexer (2:1 MUX) switches between the Thunderbolt™ technology Low Speed UART transmit/receive pair and DisplayPort Main Link 1.

The MUXs are controlled by 4 input pins: TRI#, DP_EN#, 10G_EN, and CAD_IN (cable detect from the connector). The HD3SS0001 is packaged in a small 3x3mm 24-pin QFN, operates from a single 3.3V supply, and supports an ambient temperature range of -40°C to 85°C.

FUNCTIONAL DIAGRAM



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Thunderbolt is a trademark of Intel Corp.

DisplayPort is a trademark of VESA Standards Association.

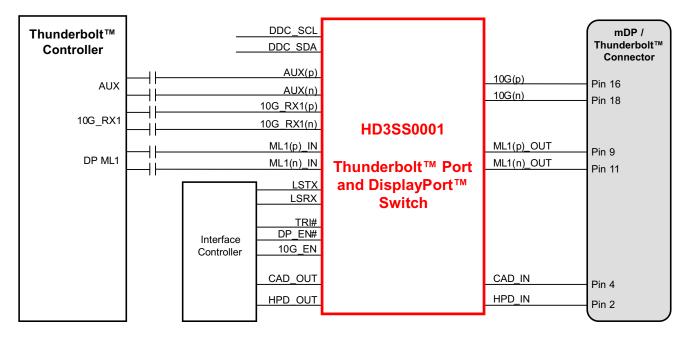
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

TYPICAL APPLICATION



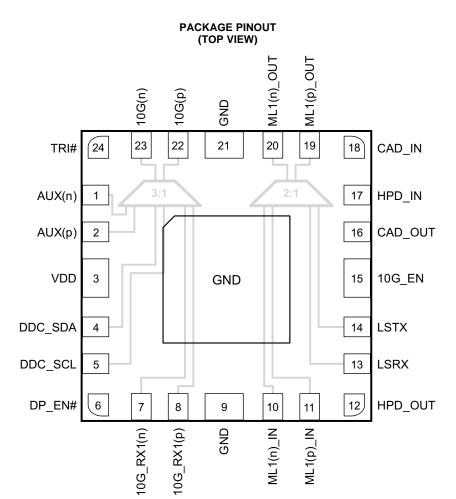
TRUTH TABLE

		LOGICAL II	NPUT TO SE	T ⁽¹⁾	EFFECT			
MODE	TRI#	DP_EN#	10G_EN	CAD_IN	2:1 MUX SELECTION ⁽²⁾	3:1 MUX SELECTION ⁽²⁾	PULL-UP RESISTOR on 10G(n)	
Thunderbolt™	1	1	1	Х	LS	10G	Disconnected	
Protocol	0	1	1	Х	LS	Tri-stated	Disconnected	
Disale: Deut	1	0	0	0	ML	AUX	Connected	
DisplayPort	0	0	0	0	Tri-Stated	Tri-stated	Connected	
TMDO	1	0	0	1	ML	DDC	Connected	
TMDS	0	0	0	1	Tri-Stated	Tri-stated	Connected	
Detect Mode	Х	1	0	Х	LS	Tri-Stated	Connected	
[Invalid]	Х	0	1	Х	Tri-Stated	Tri-Stated	Disconnected	

^{(1) &}quot;X" = Don't Care.

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⁽²⁾ MUX Selection names are abbreviated.



MUX PIN MAPPING(1)

CONTROLLER-SIDE PIN	Connector-Side Pin		
AUX(n)			
DDC_SDA	10G(n)		
10G_RX1(n)			
AUX(p)			
DDC_SCL	10G(p)		
10G_RX1(p)			
ML1(p)_IN	MI 4(n) OUT		
LSTX	ML1(p)_OUT		
ML1(n)_IN	MI 1(a) OLIT		
LSRX	ML1(n)_OUT		

(1) NOTE: The HD3SS0001 can tolerate polarity inversions for the differential signals denoted by the (p) and (n) terminology, to ease potential board routing issues. LSTX/LSRX cannot be swapped, since LSRX is buffered and therefore unidirectional. Also, note that the integrated pullup on 10G(n) and the integrated pulldown on 10G(p) cannot be swapped.



PIN FUNCTIONS

	PIN		SYSTEM	DESCRIPTION				
NO.	NAME	I/O	SIDE	DESCRIPTION				
11	ML1(p)_IN			DisplayPort MainLink1(p) input				
10	ML1(n)_IN			DisplayPort MainLink1(n) input				
24	TRI#		Controller	Tri-State control (see TRUTH TABLE)				
6	DP_EN#	I		DisplayPort Enable, active-low (see TRUTH TABLE)				
15	10G_EN			10.3Gbps Mode Enable (see TRUTH TABLE)				
18	CAD_IN		Connector	Cable Detect				
17	HPD_IN		Connector	Hot Plug Detect				
2	AUX(p)			AUX Positive Signal				
1	AUX(n)		Controller	AUX Negative Signal				
5	DDC_SCL			DDC Clock				
4	DDC_SDA			DDC Data				
14	LSTX	1/0		UART TX Signal				
13	LSRX	1/0		UART RX Signal				
22	10G(p)			10G_RX1(p) or AUX(p) or DDC_SCL, with pull-down				
23	10G(n)		Connector	10G_RX1(n) or AUX(n) or DDC_SDA, with pull-up				
19	ML1(p)_OUT		Connector	DisplayPort MainLink1(p) output or LSTX				
20	ML1(n)_OUT			DisplayPort MainLink1(n) output or LSRX				
8	10G_RX1(p)			10.3Gbps Positive Signal				
7	10G_RX1(n)	0		10.3Gbps Negative Signal				
16	CAD_OUT			Cable Detect				
12	HPD_OUT		Controller	Hot Plug Detect				
3	V_{DD}	Dannan		Power supply				
9, 21, Center Pad	GND	Power Supply		Reference ground				

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted)

		VAL	UNIT		
		MIN	MAX		
Supply voltage range ⁽²⁾	V_{DD}	-0.5	4	V	
\/altaga ranga	Differential I/O	-0.5	4	\	
Voltage range	Control pin/buffers	-0.5	V _{DD} +0.5	٧	
Clastrostatia diasharas	Human body model (3)		±1,500	V	
Electrostatic discharge	Charged-device model ⁽⁴⁾		±500	V	
Continuous power dissipation See Power Characteristics See Power Chara			r Characteristic	cs	

⁽¹⁾ Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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⁽²⁾ All voltage values, except differential voltages, are with respect to network ground terminal.

⁽³⁾ Tested in accordance with JEDEC/ESDA JS-001-2011

⁽⁴⁾ Tested in accordance with JEDEC JESD22 C101-E



THERMAL INFORMATION

over operating free-air temperature range (unless otherwise noted)

	TUEDMAL METRIC(1)	HD3SS0001	LINUTO
	THERMAL METRIC ⁽¹⁾	24-PIN VQFN (RLL)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	41.5	
θ _{JCtop}	Junction-to-case (top) thermal resistance	43.1	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	6.3	90.00
θ_{JB}	Junction-to-board thermal resistance	11.2	°C/W
ΨЈΤ	Junction-to-top characterization parameter	1.2	
ΨЈВ	Junction-to-board characterization parameter	11.2	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

POWER CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX ⁽¹⁾	UNIT
I_{DD}	Supply Current in Active Mode	Outputs Floating		1.0	1.3	mA
I _{DETECT}	Supply Current in Detect Mode	DP_EN# = 1, 10G_EN = 0		26	50	μΑ
P_D	Power Dissipation in Active Mode			3.3	4.7	mW
P _{Detect}	Power Dissipation in Detect Mode			80	150	μW

⁽¹⁾ The maximum ratings are simulated for $V_{DD} = 3.6V$.

Product Folder Links: HD3SS0001

TEXAS INSTRUMENTS

RECOMMENDED OPERATING CONDITIONS

Typical values for all parameters are at V_{DD} = 3.3V and T_A = 25°C. (Temperature limits are specified by design)

	PARAMETER	NOTES/CONDITIONS	MIN	TYP	MAX	UNIT
V_{DD}	Supply voltage		3.0	3.3	3.6 ⁽¹⁾	V
T _A	Operating free-air temperature		-40		85	°C
\/	lanut high valtage	CAD_IN, HPD_IN ⁽²⁾ , TRI#, DP_EN#, and 10G_EN	2.0		V_{DD}	V
V_{IH}	Input high voltage	ML1(n)_OUT (when 2:1 MUX selects LS)	2.0		V_{DD}	v
V	lanut laur valtaga	CAD_IN, HPD_IN ⁽²⁾ , TRI#, DP_EN#, and 10G_EN	-0.1		0.8	V
V_{IL}	Input low voltage	ML1(n)_OUT (when 2:1 MUX selects LS)	-0.1		0.8	V
1/	Output high voltage	CAD_OUT, HPD_OUT	2.7		V_{DD}	V
V _{OH}	Output high voltage	LSRX (when 2:1 MUX selects LS)	2.7		$V_{DD}^{(1)}$	V
V	Output low voltage	CAD_OUT, HPD_OUT	0.0		0.1	V
V_{OL}	Output low voltage	LSRX (when 2:1 MUX selects LS)			0.1	V
	TRI#, DP_EN#, 10G_EN, CAD_IN, and HPD_IN; $V_{DD} = 3.6V$, $V_{IN} = V_{DD}$			5		
I _{IH}	High-level input current	ML1(n)_OUT; V_{DD} = 3.6V; V_{IN} = V_{DD} (when 2:1 MUX selects LS)			3.75	μA
	Low-level input current	TRI#, DP_EN#, 10G_EN, CAD_IN, and HPD_IN; V _{DD} = 3.6V, V _{IN} = GND			100	nA
I _{IL}	Low-level input current	ML1(n)_OUT; V_{DD} = 3.6V, V_{IN} = GND (when 2:1 MUX selects LS)			100	ΠA
$V_{\text{I/O}_\text{Diff}}$	Differential I/O voltage	AUX(p)/AUX(n), 10G_RX1(p)/ 10G_RX1(n), ML1(p)_IN/ML1(n)_IN, 10G(p)/10G(n), and ML1(p)_OUT/ML1(n)_OUT when MUX's are connected to Differential Signals.	0		1.8	Vpp
V _{I/O_CM}	Common mode I/O voltage	AUX(p)/AUX(n), 10G_RX1(p)/10G_RX1(n), ML1(p)_IN/ML1(n)_IN, 10G(p)/ 10G(n), and ML1(p)_OUT/ML1(n)_OUT when MUX's are connected to Differential Signals.	0		2.0	V

⁽¹⁾ V_{DD} range supports 3.0V to 3.6V, but for Thunderbolt products it is anticipated that the V_{DD} must be maintained at less than or equal to 3.4V to ensure that the V_{OH} on the LSRx do not exceed 3.4V.

ELECTRICAL CHARACTERISTICS

(under recommended operation conditions)

PARAMETER		CONDITIONS	MIN TYP	MAX	UNIT	
Thunde	rbolt™ Technology 10.3Gbps Link: 10G	RX1(p), 10G_RX1(n) ⁽¹⁾	•	•		
R_L	Differential Return Loss	f = 5.0 GHz	-20		dB	
IL	Differential Insertion Loss	f = 5.0 GHz	-1.5		dB	
O _{IRR}	Differential Off Isolation	f = 5.0GHz (see Figure 3)	-24		dB	
X _{TALK}	Differential Crosstalk	f = 5.0 GHz	-35		dB	
BW	Bandwidth	-3 dB	10		GHz	
t _{PD}	Propagation Delay(from input to output)	R_{sc} and R_L = 50 Ω (see Figure 2)		200	ps	
T _{SKEW}	Intra-Pair Skew Added	R_{sc} and $R_L = 50 \Omega$ (see Figure 2)		4	ps	
C _{ON}	Outputs ON Capacitance	V _I = 0 V, Outputs Open, Switch ON	1.5		pF	
C _{OFF}	Outputs OFF Capacitance	VI = 0 V, Outputs Open Switch OFF	1		pF	
R _{ON}	Output ON resistance	$V_{DD} = 3.3 \text{ V}, I_{O} = -15 \mu\text{A}$	7.5		Ω	
ΔR _{ON}	On resistance match between pairs of the same channel	$V_{DD} = 3.3V; I_{O} = -15 \mu A$		1	Ω	
T _{ON}	Control Line Change to MUX Output	Con Figure 4		400		
T _{OFF} Switched		See Figure 1		10	μs	

⁽¹⁾ These values apply for CAD_IN tri-stated, unless otherwise noted.

Product Folder Links :HD3SS0001

⁽²⁾ HPD_IN is 5V tolerant.

ELECTRICAL CHARACTERISTICS (continued)

(under recommended operation conditions)

(under r	ecommended operation conditions)				
	PARAMETER	CONDITIONS	MIN TYP	MAX	UNIT
Display	Port Link: ML1(p)_IN, ML1(n)_IN				
R_L	Differential Return Loss	f = 2.7 GHz	-16		dB
IL	Differential Insertion Loss	f = 2.7 GHz; V _{CM} = 0 V	-0.8		dB
O _{IRR}	Differential Off-Isolation	f = 2.7 GHz (see Figure 3)	-20		dB
X _{TALK}	Differential Crosstalk	f = 2.7 GHz	-35		dB
BW	Differential Bandwidth	-3 dB	7		GHz
t _{PD}	Propagation Delay(from input to output)	R_{SC} and R_L = 50 Ω (see Figure 2)		200	ps
T _{SKEW}	Intra-pair Skew Added	R_{SC} and $R_L = 50 \Omega$ (see Figure 2)		4	ps
C _{ON}	Outputs ON Capacitance	VI = 0 V; Outputs Open; Switch ON	1.5		pF
C _{OFF}	Outputs OFF Capacitance	V _I = 0 V; Outputs Open; Switch OFF	1		pF
R _{ON}	Output ON resistance	V_{DD} = 3.3 V; I_{O} = -15 mA; V_{CM} = 0.5 V to 1.5 V; CAD_IN = 0 V	6	8	Ω
ΔR_{ON}	On resistance match between pairs of the same channel	V_{DD} = 3.3 V; I_{O} = -15 mA; V_{CM} = 0.5 V to 1.5 V		1	Ω
T _{ON}	Control Line Change to MUX Output Switched	See Figure 1		400 10	μs
	rbolt™ Technology Low Speed UART : I	LSTX		I	
C _{ON}	Outputs ON capacitance	V _I = 0 V , Outputs Open, Switch ON	8		pF
C _{OFF}	Outputs OFF capacitance	V _I = 0 V, Outputs Open, Switch OFF	3		pF
R _{ON}	Output ON resistance	V _{DD} = 3 V, V _{CM} = 0 V to 3 V, I _O = -1 mA CAD_IN = 0 V	12	19	Ω
t _{PD}	Propagation Delay	LSTX to ML1(p)_OUT	200		ps
Display	Port: AUX(p), AUX(n)	1 ""	Ш.		
C _{ON}	Outputs ON Capacitance	V _I = 0 V; Outputs Open; Switch ON	6		pF
C _{OFF}	Outputs OFF Capacitance	V _I = 0 V; Outputs Open; Switch OFF	3		pF
R _{ON}	Output ON resistance	$V_{DD} = 3.3V; I_{O} = -10 \text{ mA}; AUX(p) = 0.3 V;$ $AUX(n) = 3.0 V; CAD_IN = 0 V$	12		Ω
ΔR _{ON}	On resistance match between pairs of the same channel	$V_{DD} = 3.3 \text{ V}; I_{O} = -10 \text{ mA};$ $V_{CM} = 0.5 \text{ V to } 1.5 \text{ V}$		1	Ω
T _{ON}	Control line change to Mux output			40	ms
T _{OFF}	switched	See Figure 2		10	μs
	rbolt Technology Low Speed UART : LS	RX			
C _{ON}	Outputs capacitance		3		pF
Z _O	Output impedance	V _{DD} = 3.3 V	60		Ω
t _{PD}	Propagation delay	ML1(n)_OUT to LSRX	3.2		ns
t _r	Rise Time	V _{DD} = 3 V	3		ns
t _f	Fall Time	V _{DD} = 3 V	3		ns
T _{ON}	Control line change to MUX Output			400	μs
T _{OFF}	Switched	See Figure 1		10	μs

TEXAS INSTRUMENTS

ELECTRICAL CHARACTERISTICS (continued)

(under recommended operation conditions)

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
Display	/Port : DDC_SCL, DDC_SDA					
C _{ON}	Outputs ON capacitance	V _I = 0 V, Outputs Open, Switch ON		9		pF
C _{OFF}	Outputs OFF capacitance	V _I = 0 V, Outputs Open, Switch OFF		3		pF
R _{ON}	Output ON resistance	V_{DD} = 3.3 V, I_{O} = -10 mA, V_{CM} = 0.4 V, CAD_IN = 3.3 V		80	150	Ω
T _{ON}	Control line change to MUX output	See Figure 1			400	
T _{OFF}	switched				10	μs
UART a	and 10G MUX Outputs : LSTX/LSRX/10G	(p)/10G(n)				
R1	Integrated Pullup Resistance	10G(n) pin when in DP, TMDS, or Detect Mode		87	105	kΩ
R2	Integrated Pulldown Resistance	10G(p) pin when in DP, TMDS, or Detect Mode, or VDD = 0V		87	105	kΩ
R_{PU}	Integrated pullup resistance	LSTX		8.7		kΩ
R _{PD}	Integrated pulldown resistance	LSRX		1.2		ΜΩ

TEST DIAGRAMS

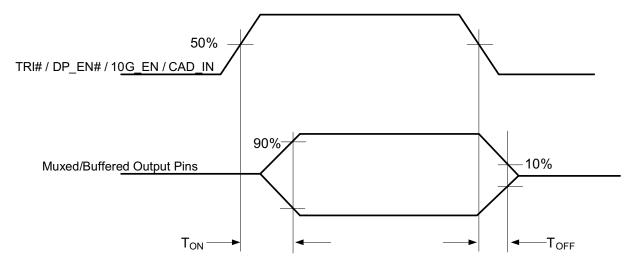
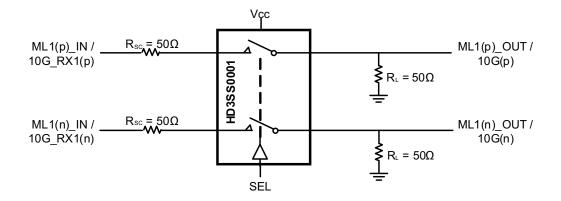
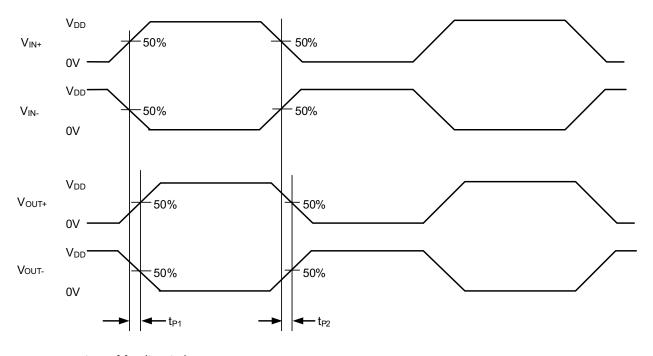


Figure 1. Control Line Change to Switched Signals







 $t_{PD} = Max(t_{p1}, t_{p2})$

 $t_{SK(O)}$ = Difference between t_{PD} for any two pairs of outputs

 $t_{SK(b-b)}$ = Difference between t_{P1} and t_{P2} of same pair

Figure 2. Propagation Delay and Skew



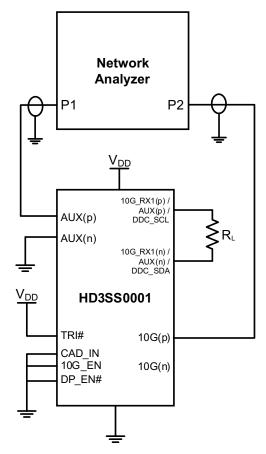


Figure 3. Off-Isolation Measurement Setup



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
HD3SS0001RLLR	ACTIVE	VQFN	RLL	24	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	3SS001	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

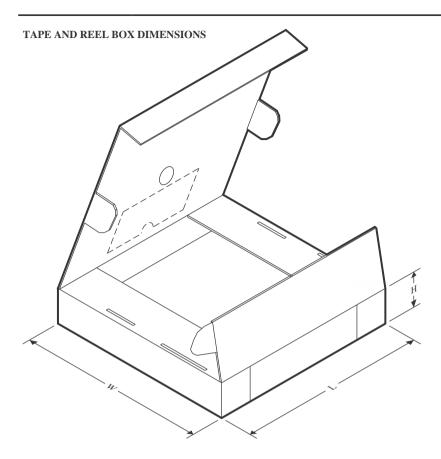


*All dimensions are nominal

	Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ĺ	HD3SS0001RLLR	VQFN	RLL	24	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

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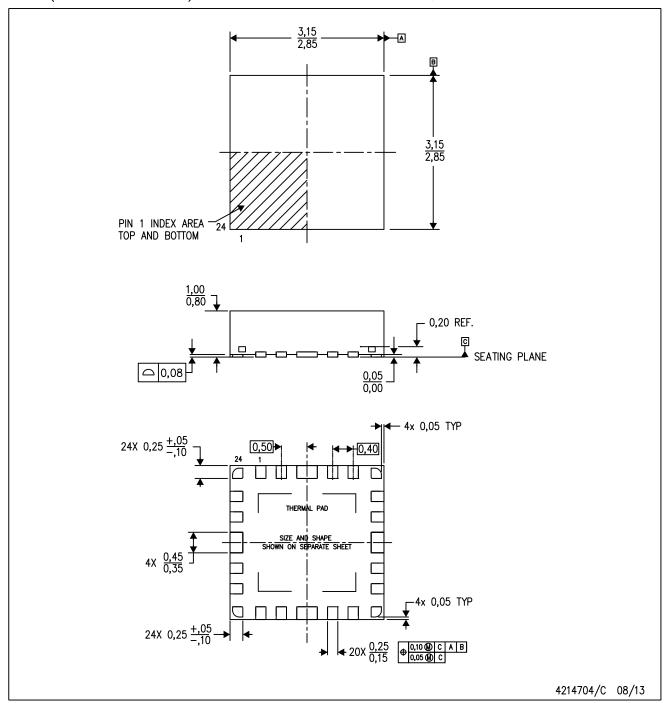


*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	HD3SS0001RLLR	VQFN	RLL	24	3000	346.0	346.0	33.0	

RLL (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD

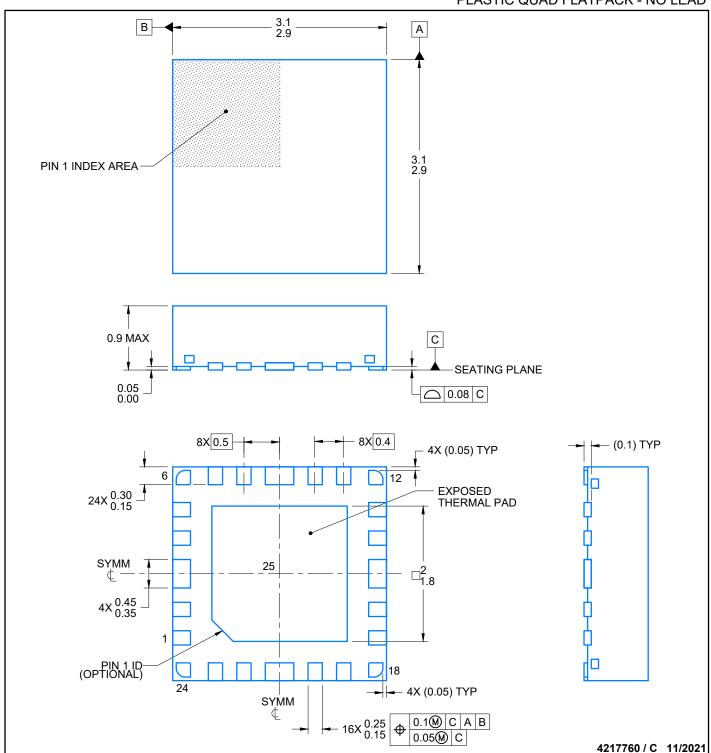


NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.



PLASTIC QUAD FLATPACK - NO LEAD

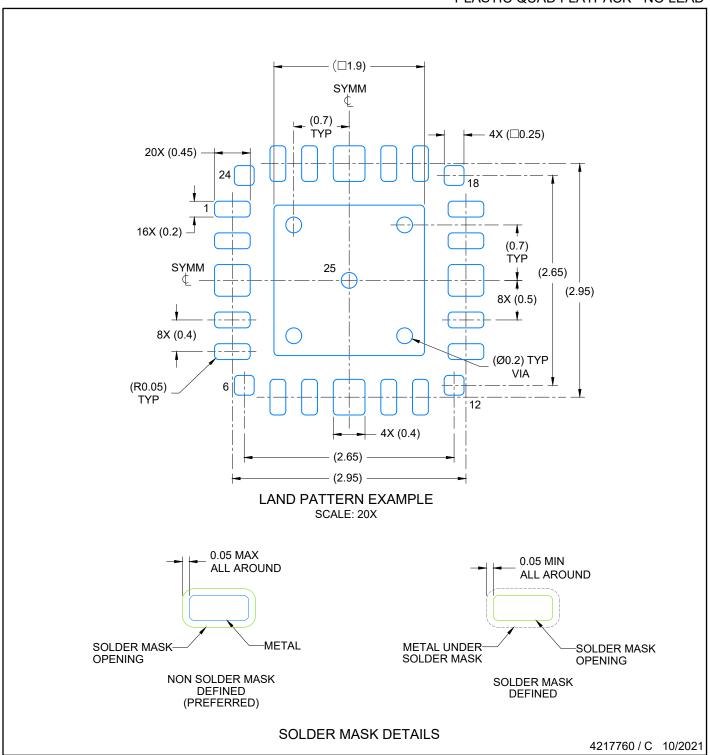


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

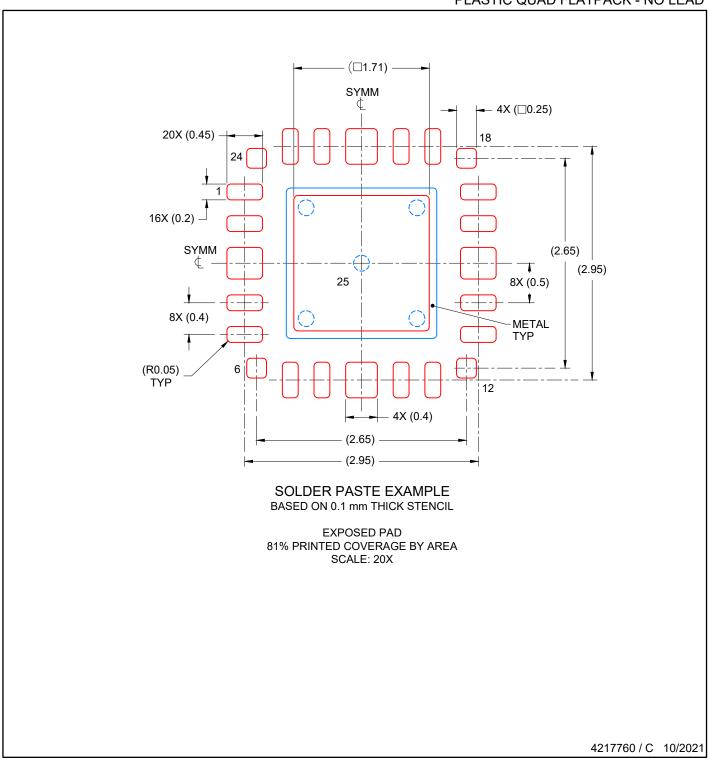


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..



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